

Features

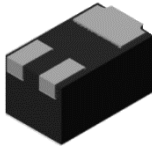
- $BV_{CEO} > 45V$
- $I_C = 100mA$ High Collector Current
- $P_D = 1W$ Power Dissipation
- $0.6mm^2$ Package Footprint, 13 Times Smaller than SOT23
- 0.4mm-High Package Minimizing Off-Board Profile
- Sidewall Tin Plating for Wettable Flanks in AOI
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The BC847BLP4Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

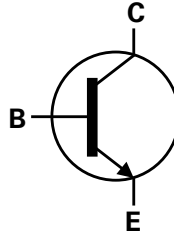
Mechanical Data

- Package: U-DFN1006-3/SWP (Type UX)
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.0008 grams (Approximate)

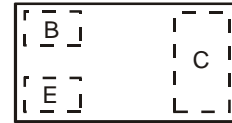
U-DFN1006-3/SWP
(Type UX)



Bottom View



Device Symbol



Top View
Device Schematic

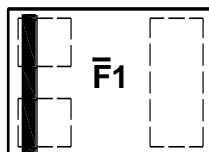
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
BC847BLP4Q-7	U-DFN1006-3/SWP (Type UX)	F1	7	8	3,000	Reel
BC847BLP4Q-7B	U-DFN1006-3/SWP (Type UX)	F1	7	8	10,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

U-DFN1006-3/SWP
(Type UX)



F1 = Product Type Marking Code

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EB0}	6	V
Collector Current	I _C	100	mA
Peak Pulse Collector Current	I _{CM}	200	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	(Note 5) 0.255	W
		(Note 6) 0.890	
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 5) 490	°C/W
		(Note 6) 140	
Thermal Resistance, Junction to Lead	R _{θJL}	49	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A

- Notes:
5. For a device mounted on the minimum recommended pad layout of 2oz copper on a single-sided 1.6mm FR4 PCB; device is measured under still-air conditions whilst operating in steady-state condition.
 6. Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
 8. Refer to JEDEC specification JS-001.

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

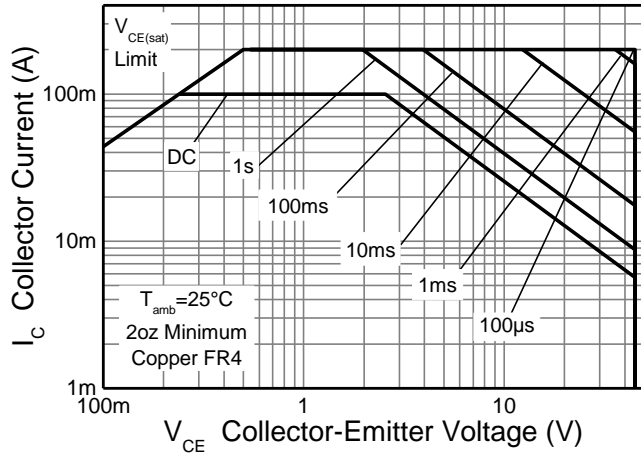


Fig.1 Safe Operating Area

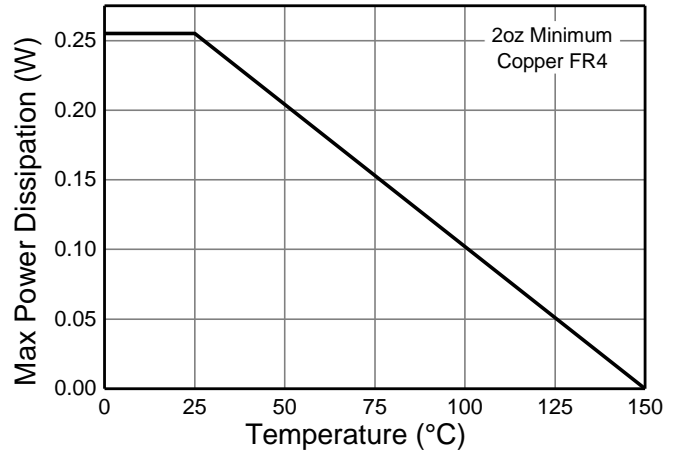


Fig.2 Derating Curve

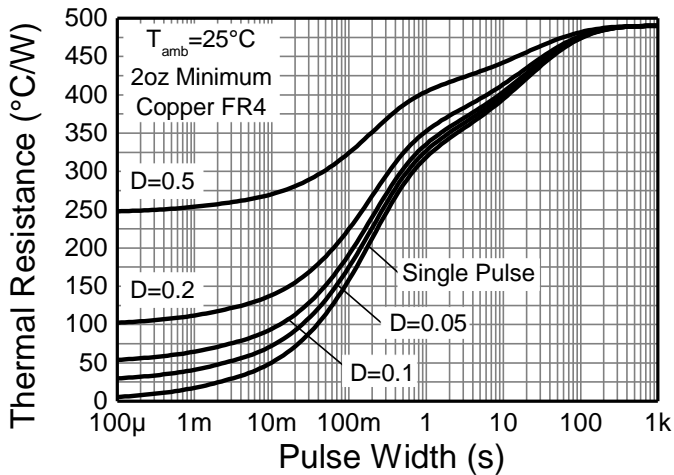


Fig.3 Transient Thermal Impedance

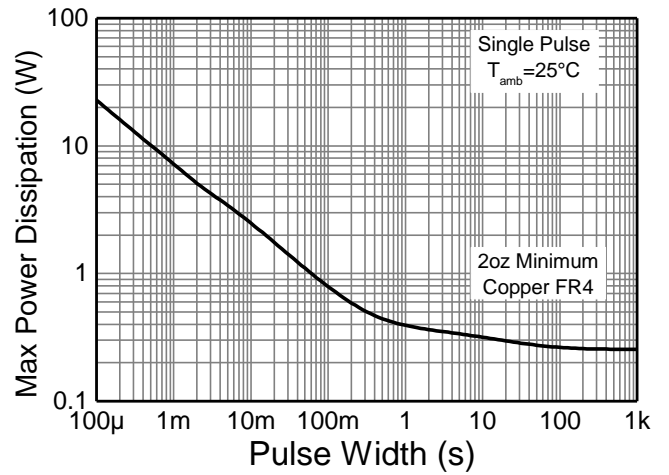


Fig.4 Pulse Power Dissipation

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	—	—	V	$I_C = 10\mu\text{A}, I_B = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	45	—	—	V	$I_C = 10\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV_{EBO}	6	—	—	V	$I_E = 1\mu\text{A}, I_C = 0$
Collector-Cutoff Current	I_{CBO}	—	—	15 5	nA μA	$V_{CB} = 30\text{V}$ $V_{CB} = 30\text{V}, T_A = +150^\circ\text{C}$
DC Current Gain	h_{FE}	200	350	450	—	$V_{CE} = 5\text{V}, I_C = 2\text{mA}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	—	80 200	250 600	mV	$I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5\text{mA}$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	—	700 900	—	mV	$I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5\text{mA}$
Base-Emitter Voltage (Note 9)	$V_{BE(on)}$	580 —	640 725	700 770	mV	$V_{CE} = 5\text{V}, I_C = 2\text{mA}$ $V_{CE} = 5\text{V}, I_C = 10\text{mA}$
Gain Bandwidth Product	f_T	100	—	—	MHz	$V_{CE} = 5\text{V}, I_C = 10\text{mA},$ $f = 100\text{MHz}$
Collector-Base Capacitance	C_{cbo}	—	3	—	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

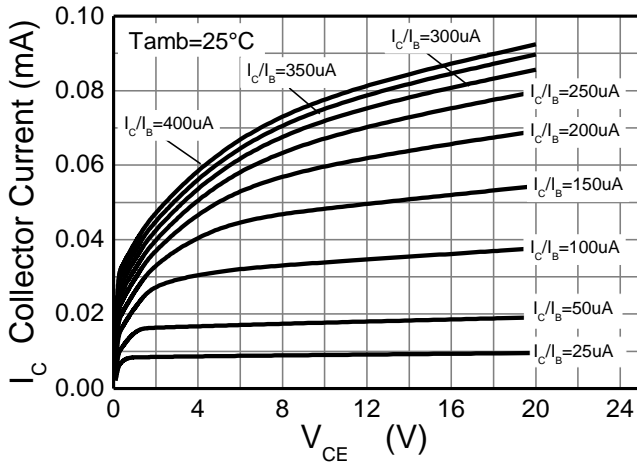


Fig.5 $I_C \text{ v } V_{CE}$

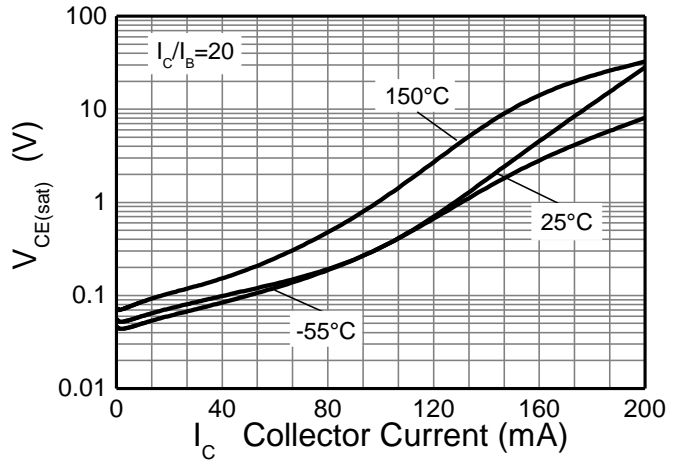


Fig.6 $V_{CE(sat)} \text{ v } I_C$

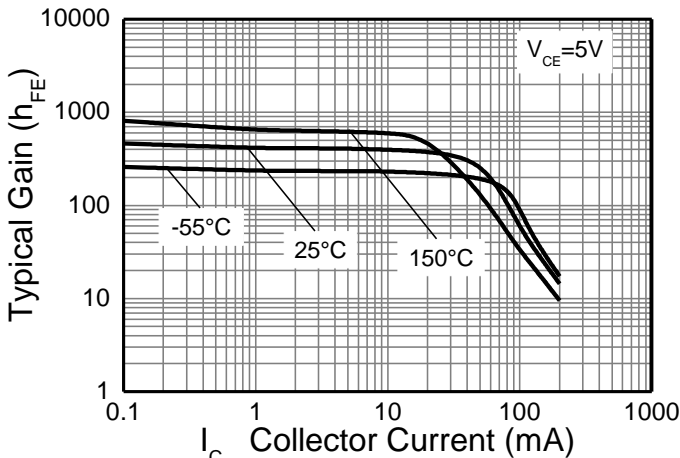


Fig.7 $h_{FE} \text{ v } I_C$

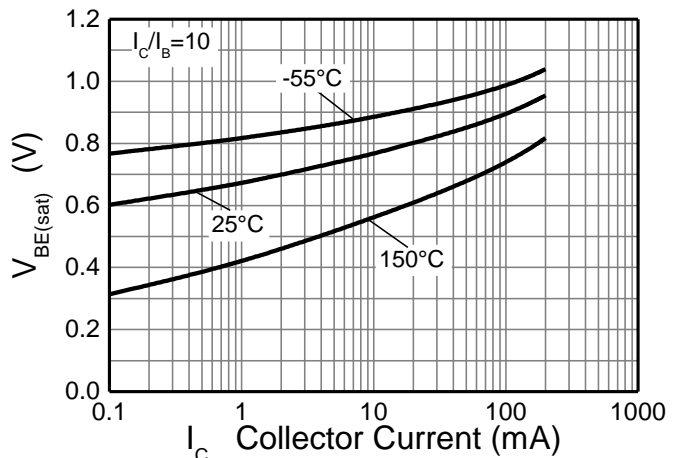


Fig.8 $V_{BE(sat)} \text{ v } I_C$

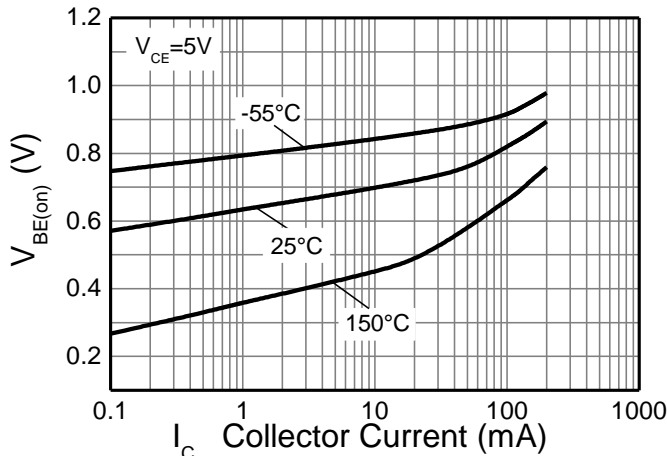
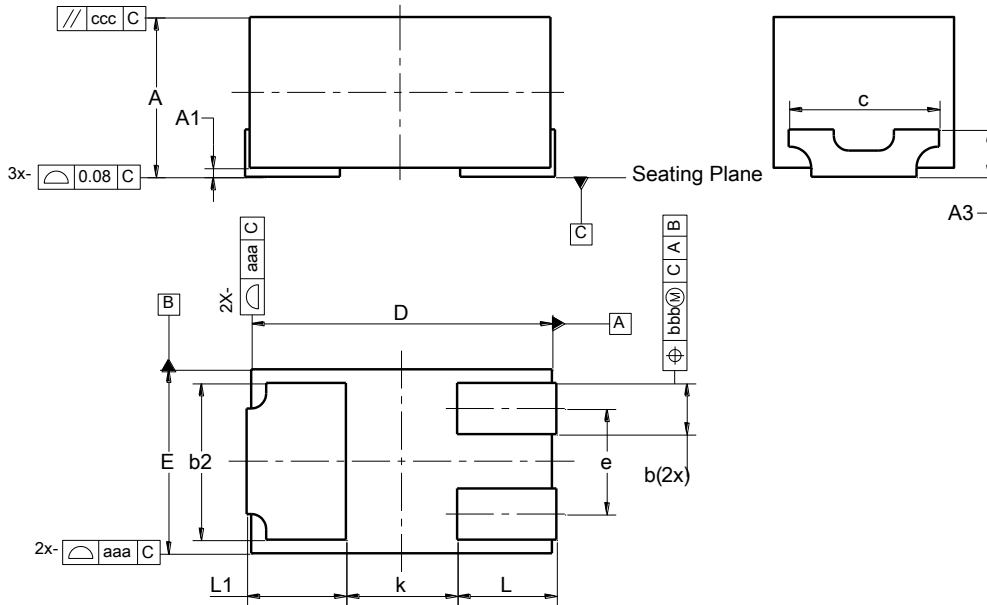


Fig.9 $V_{BE(on)} \text{ v } I_C$

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN1006-3/SWP (Type UX)



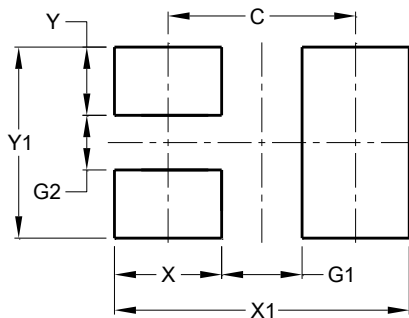
U-DFN1006-3/SWP (Type UX)			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0.00	0.05	0.03
A3	0.17 REF		
b	0.12	0.22	0.17
b2	0.47	0.57	0.52
D	0.95	1.05	1.00
E	0.55	0.65	0.60
e	--	--	0.35
k	0.37 REF		
L	0.28	0.38	0.33
L1	0.28	0.38	0.33
c	0.50 REF		
aaa	0.15		
bbb	0.05		
ccc	0.05		
All Dimensions in mm			

Note: 10. Sidewall tin-plated package for wettable flanks in AOI.

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN1006-3/SWP (Type UX)



Dimensions	Value (in mm)
C	0.700
G1	0.300
G2	0.200
X	0.400
X1	1.100
Y	0.250
Y1	0.700

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